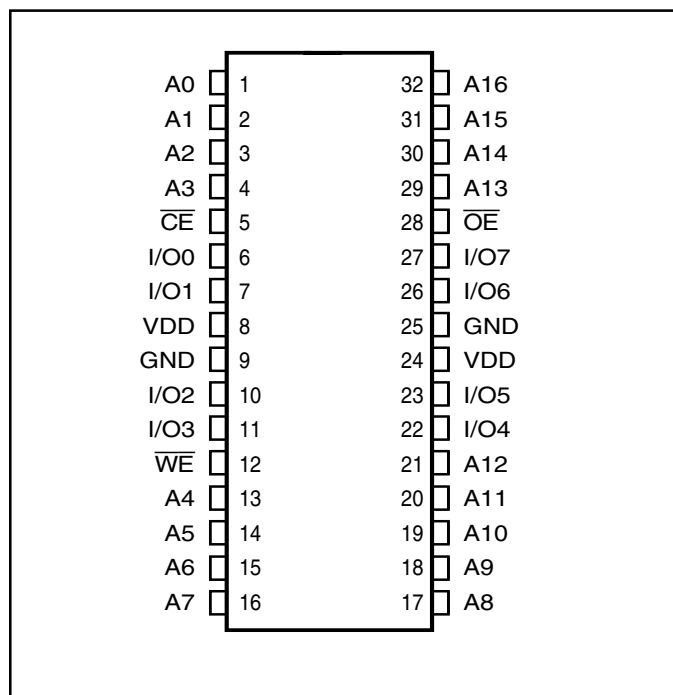


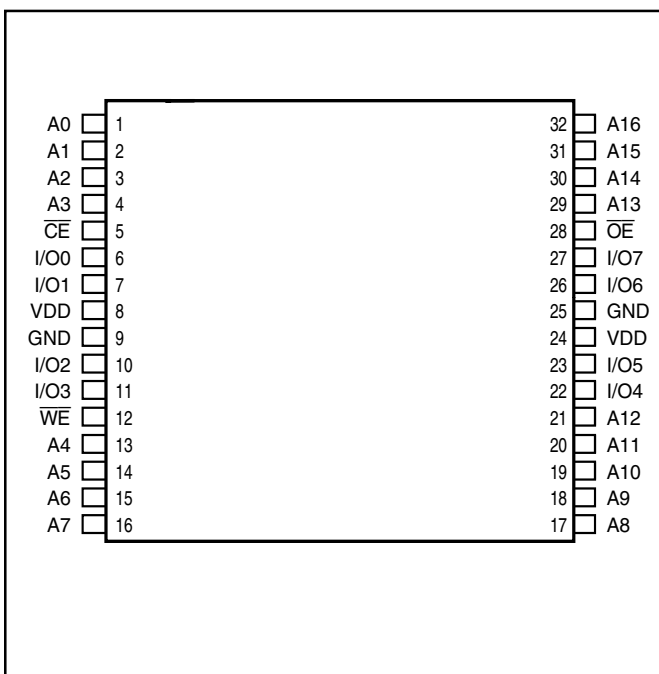
## PIN CONFIGURATION

### 32-Pin SOJ



## PIN CONFIGURATION

### 32-Pin TSOP (Type II) (T) 32-Pin sTSP (Type I) (H)

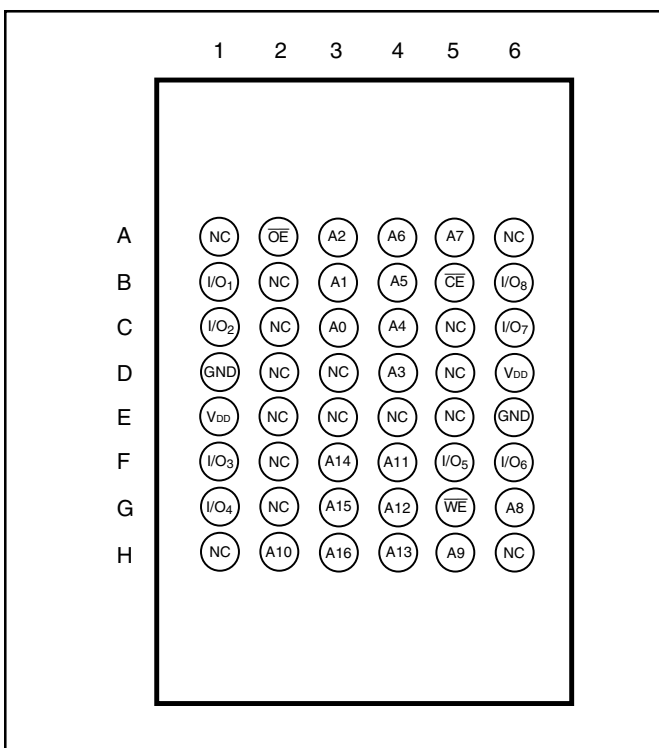


## PIN DESCRIPTIONS

A0-A16	Address Inputs
$\overline{CE}$	Chip Enable Input
$\overline{OE}$	Output Enable Input
$\overline{WE}$	Write Enable Input
I/O0-I/O7	Bidirectional Ports
VDD	Power
GND	Ground

## PIN CONFIGURATION

### 48-mini BGA (B) (6 mm x 8 mm)



## TRUTH TABLE

Mode	$\overline{WE}$	$\overline{CE}$	$\overline{OE}$	I/O Operation	V <sub>DD</sub> Current
Not Selected (Power-down)	X	H	X	High-Z	I <sub>SB1</sub> , I <sub>SB2</sub>
Output Disabled	H	L	H	High-Z	I <sub>CC1</sub> , I <sub>CC2</sub>
Read	H	L	L	D <sub>OUT</sub>	I <sub>CC1</sub> , I <sub>CC2</sub>
Write	L	L	X	D <sub>IN</sub>	I <sub>CC1</sub> , I <sub>CC2</sub>

## ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>

Symbol	Parameter	Value	Unit
V <sub>TERM</sub>	Terminal Voltage with Respect to GND	-0.5 to V <sub>DD</sub> +0.5	V
T <sub>STG</sub>	Storage Temperature	-65 to +150	°C
P <sub>T</sub>	Power Dissipation	1.5	W
V <sub>DD</sub>	V <sub>DD</sub> Related to GND	-0.2 to +3.9	V

### Note:

1. Stress greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

## OPERATING RANGE (V<sub>DD</sub>)

Range	Ambient Temperature	V <sub>DD</sub> (15 ns)	V <sub>DD</sub> (12 ns)
Commercial	0°C to +70°C	2.5V-3.6V	3.3V ± 10%
Industrial	-40°C to +85°C	2.5V-3.6V	3.3V ± 10%
Automotive	-40°C to +125°C	2.5V-3.6V	3.3V ± 10%

## DC ELECTRICAL CHARACTERISTICS (Over Operating Range)

**$V_{DD} = 2.5V-3.6V$**

Symbol	Parameter	Test Conditions	Min.	Max.	Unit
$V_{OH}$	Output HIGH Voltage	$V_{DD} = \text{Min.}, I_{OH} = -1.0 \text{ mA}$	2.3	—	V
$V_{OL}$	Output LOW Voltage	$V_{DD} = \text{Min.}, I_{OL} = 1.0 \text{ mA}$	—	0.4	V
$V_{IH}$	Input HIGH Voltage		2.0	$V_{DD} + 0.3$	V
$V_{IL}$	Input LOW Voltage <sup>(1)</sup>		-0.3	0.8	V
$I_{LI}$	Input Leakage	$GND \leq V_{IN} \leq V_{DD}$	-2	2	$\mu A$
$I_{LO}$	Output Leakage	$GND \leq V_{OUT} \leq V_{DD}$ , Outputs Disabled	-2	2	$\mu A$

### Note:

- $V_{IL}(\text{min.}) = -0.3V_{DC}$ ;  $V_{IL}(\text{min.}) = -2.0V_{AC}$  (pulse width < 10 ns). Not 100% tested.  
 $V_{IH}(\text{max.}) = V_{DD} + 0.3V_{DC}$ ;  $V_{IH}(\text{max.}) = V_{DD} + 2.0V_{AC}$  (pulse width < 10 ns). Not 100% tested.

## DC ELECTRICAL CHARACTERISTICS (Over Operating Range)

**$V_{DD} = 3.3V \pm 10\%$**

Symbol	Parameter	Test Conditions	Min.	Max.	Unit
$V_{OH}$	Output HIGH Voltage	$V_{DD} = \text{Min.}, I_{OH} = -4.0 \text{ mA}$	2.4	—	V
$V_{OL}$	Output LOW Voltage	$V_{DD} = \text{Min.}, I_{OL} = 8.0 \text{ mA}$	—	0.4	V
$V_{IH}$	Input HIGH Voltage		2	$V_{DD} + 0.3$	V
$V_{IL}$	Input LOW Voltage <sup>(1)</sup>		-0.3	0.8	V
$I_{LI}$	Input Leakage	$GND \leq V_{IN} \leq V_{DD}$	-2	2	$\mu A$
$I_{LO}$	Output Leakage	$GND \leq V_{OUT} \leq V_{DD}$ , Outputs Disabled	-2	2	$\mu A$

### Note:

- $V_{IL}(\text{min.}) = -0.3V_{DC}$ ;  $V_{IL}(\text{min.}) = -2.0V_{AC}$  (pulse width < 10 ns). Not 100% tested.  
 $V_{IH}(\text{max.}) = V_{DD} + 0.3V_{DC}$ ;  $V_{IH}(\text{max.}) = V_{DD} + 2.0V_{AC}$  (pulse width < 10 ns). Not 100% tested.

**POWER SUPPLY CHARACTERISTICS<sup>(1)</sup>** (Over Operating Range)

Symbol	Parameter	Test Conditions	Options	-12 ns		-15 ns		Unit
				Min.	Max.	Min.	Max.	
I <sub>CC</sub>	V <sub>DD</sub> Dynamic Operating Supply Current	V <sub>DD</sub> = Max., I <sub>OUT</sub> = 0 mA, f = f <sub>MAX</sub>	COM.	—	35	—	30	mA
			IND.	—	45	—	40	
			AUTO	—	60	—	50	
			typ. <sup>(2)</sup>	—	20	—	20	
I <sub>CC1</sub>	Operating Supply Current	V <sub>DD</sub> = Max., I <sub>OUT</sub> = 0 mA, f = 0	COM.	—	5	—	5	mA
			IND.	—	5	—	5	
			AUTO	—	5	—	5	
I <sub>SB1</sub>	TTL Standby Current (TTL Inputs)	V <sub>DD</sub> = Max., V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> CE ≥ V <sub>IH</sub> , f = 0	COM.	—	3	—	3	mA
			IND.	—	4	—	4	
			AUTO	—	4	—	4	
I <sub>SB2</sub>	CMOS Standby Current (CMOS Inputs)	V <sub>DD</sub> = Max., CE ≥ V <sub>DD</sub> - 0.2V, V <sub>IN</sub> ≥ V <sub>DD</sub> - 0.2V, or V <sub>IN</sub> ≤ 0.2V, f = 0	COM.	—	20	—	20	uA
			IND.	—	50	—	50	
			AUTO	—	75	—	75	
			typ. <sup>(2)</sup>	—	6	—	6	

**Note:**

- At f = f<sub>MAX</sub>, address and data inputs are cycling at the maximum frequency, f = 0 means no input lines change.
- Typical values are measured at V<sub>DD</sub>=2.5V, T<sub>A</sub>=25°C. Not 100% tested.

**CAPACITANCE<sup>(1)</sup>**

Symbol	Parameter	Conditions	Max.	Unit
C <sub>IN</sub>	Input Capacitance	V <sub>IN</sub> = 0V	6	pF
C <sub>OUT</sub>	Input/Output Capacitance	V <sub>OUT</sub> = 0V	8	pF

**Note:**

- Tested initially and after any design or process changes that may affect these parameters.

AC TEST CONDITIONS

Parameter	Unit (2.5V-3.6V)	Unit (3.3V ± 10%)
Input Pulse Level	0V to V <sub>DD</sub> V	0V to V <sub>DD</sub> V
Input Rise and Fall Times	1.5ns	1.5ns
Input and Output Timing and Reference Level (V <sub>Ref</sub> )	V <sub>DD</sub> /2	V <sub>DD</sub> /2 + 0.05
Output Load	See Figures 1a and 1b	See Figures 1a and 1b

AC TEST LOADS

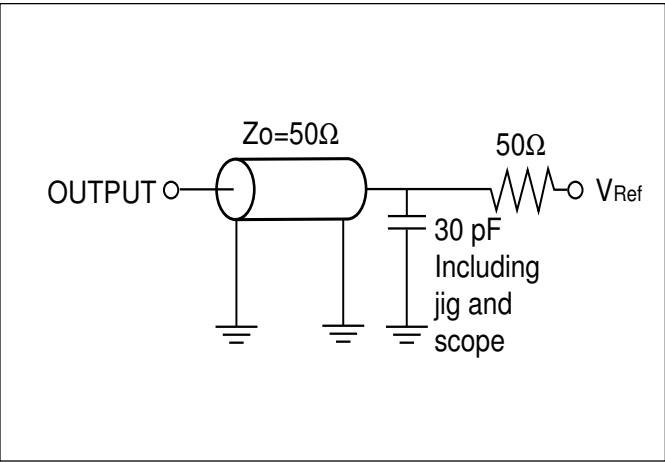


Figure 1a.

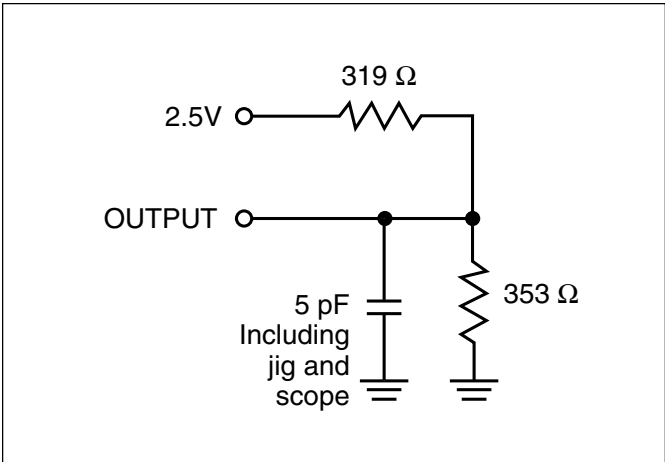


Figure 1b.

# READ CYCLE SWITCHING CHARACTERISTICS<sup>(1)</sup> (Over Operating Range)

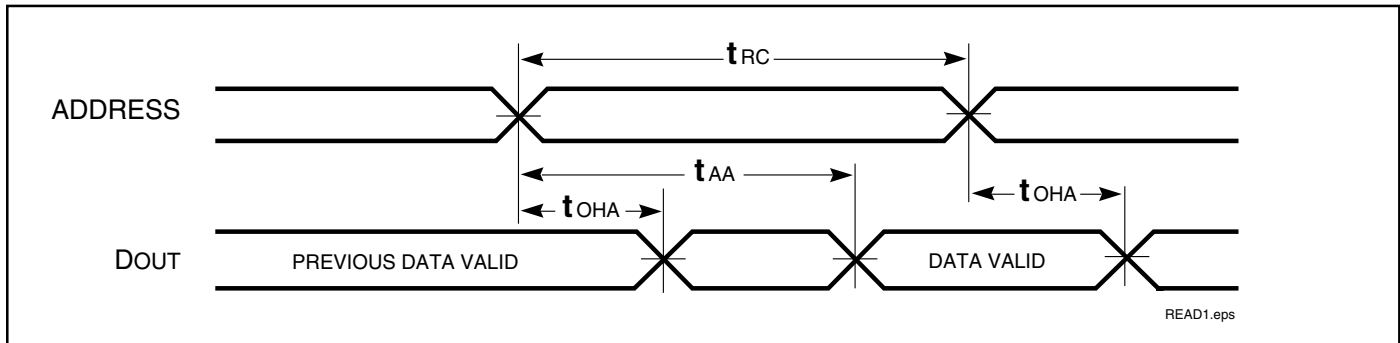
Symbol	Parameter	-12 ns		-15 ns		Unit
		Min.	Max.	Min.	Max.	
t <sub>RC</sub>	Read Cycle Time	12	—	15	—	ns
t <sub>AA</sub>	Address Access Time	—	12	—	15	ns
t <sub>OHA</sub>	Output Hold Time	3	—	3	—	ns
t <sub>ACE</sub>	$\overline{\text{CE}}$ Access Time	—	12	—	15	ns
t <sub>DOE</sub>	$\overline{\text{OE}}$ Access Time	—	6	—	7	ns
t <sub>LZOE</sub> <sup>(2)</sup>	$\overline{\text{OE}}$ to Low-Z Output	0	—	0	—	ns
t <sub>HZOE</sub> <sup>(2)</sup>	$\overline{\text{OE}}$ to High-Z Output	0	6	0	6	ns
t <sub>LZCE</sub> <sup>(2)</sup>	$\overline{\text{CE}}$ to Low-Z Output	3	—	3	—	ns
t <sub>HZCE</sub> <sup>(2)</sup>	$\overline{\text{CE}}$ to High-Z Output	0	6	0	6	ns
t <sub>PU</sub>	$\overline{\text{CE}}$ to Power Up Time	0	—	0	—	ns
t <sub>PD</sub>	$\overline{\text{CE}}$ to Power Down Time	—	12	—	15	ns

## Notes:

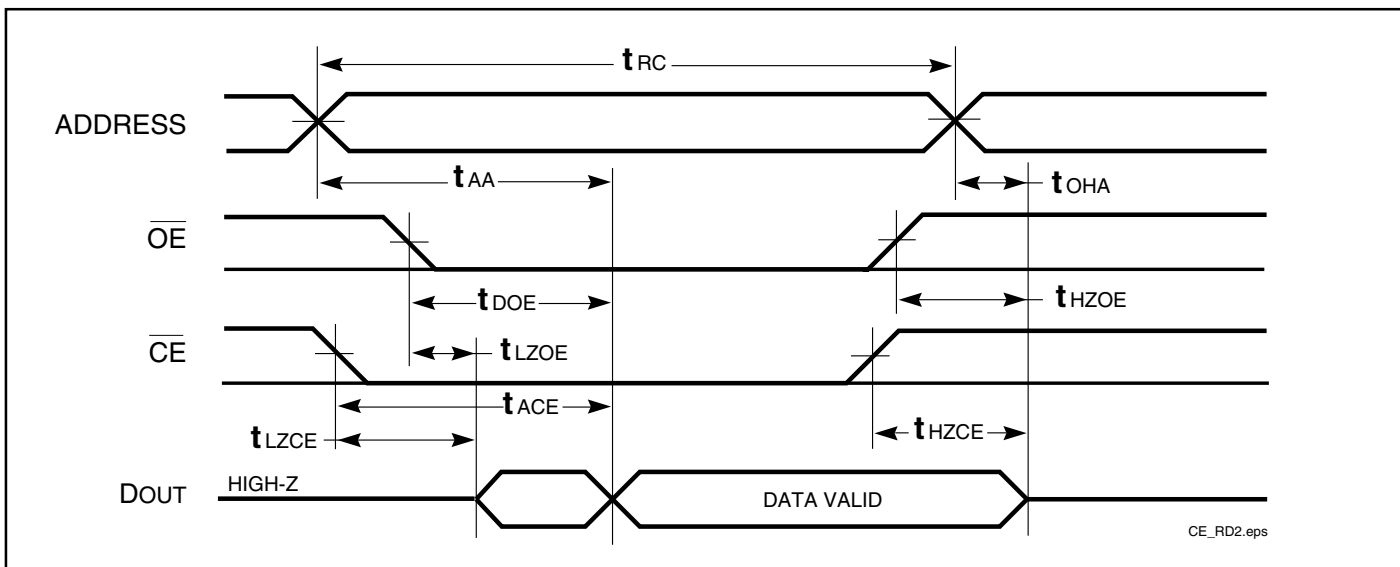
1. Test conditions assume signal transition times of 3 ns or less, timing reference levels of 1.25V, input pulse levels of 0.4V to V<sub>DD</sub>-0.3V and output loading specified in Figure 1.
2. Tested with the loading specified in Figure 1. Transition is measured  $\pm 500$  mV from steady-state voltage. Not 100% tested.

## AC WAVEFORMS

### READ CYCLE NO. 1<sup>(1,2)</sup>



### READ CYCLE NO. 2<sup>(1,3)</sup>



#### Notes:

1.  $\overline{WE}$  is HIGH for a Read Cycle.
2. The device is continuously selected.  $\overline{OE}$ ,  $\overline{CE}$  =  $V_{IL}$ .
3. Address is valid prior to or coincident with  $\overline{CE}$  LOW transitions.

## WRITE CYCLE SWITCHING CHARACTERISTICS<sup>(1,3)</sup> (Over Operating Range)

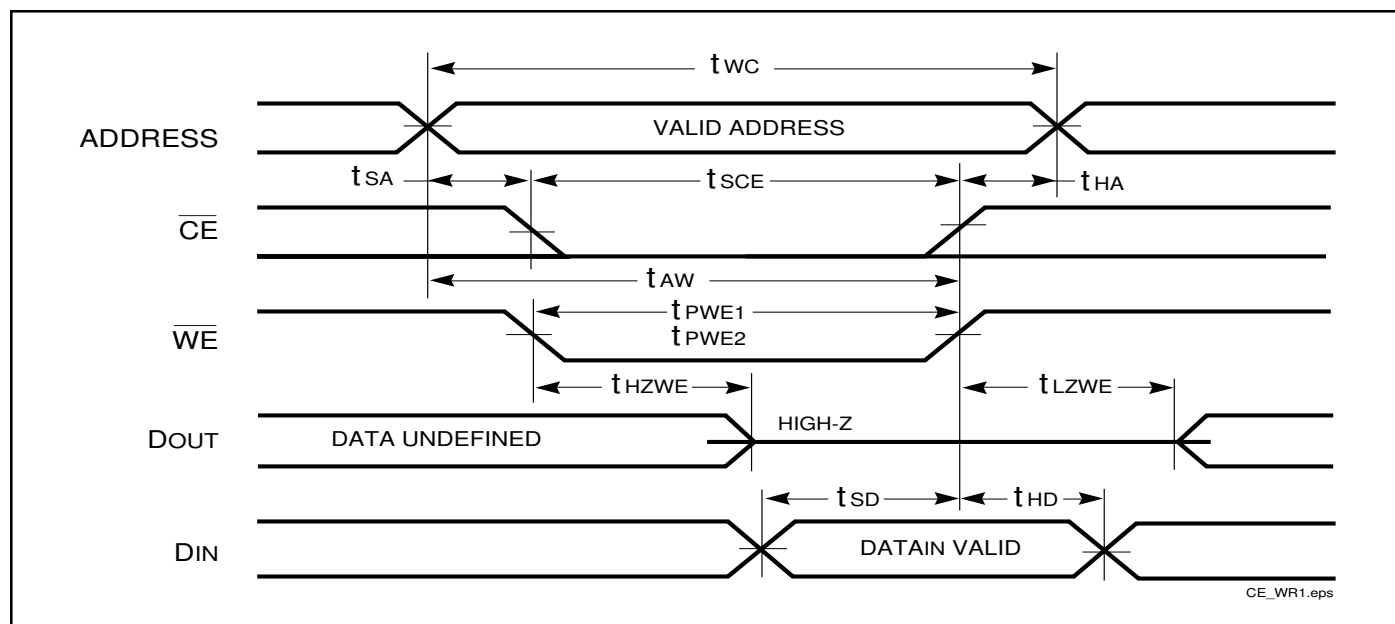
Symbol	Parameter	-12 ns		-15 ns		Unit
		Min.	Max.	Min.	Max.	
$t_{WC}$	Write Cycle Time	12	—	15	—	ns
$t_{SCE}$	$\overline{CE}$ to Write End	9	—	10	—	ns
$t_{AW}$	Address Setup Time to Write End	9	—	10	—	ns
$t_{HA}$	Address Hold from Write End	0	—	0	—	ns
$t_{SA}$	Address Setup Time	0	—	0	—	ns
$t_{PWE_1}^{(1)}$	$\overline{WE}$ Pulse Width ( $\overline{OE}$ High)	9	—	10	—	ns
$t_{PWE_2}^{(2)}$	$\overline{WE}$ Pulse Width ( $\overline{OE}$ Low)	11	—	12	—	ns
$t_{SD}$	Data Setup to Write End	9	—	9	—	ns
$t_{HD}$	Data Hold from Write End	0	—	0	—	ns
$t_{HZWE}^{(2)}$	$\overline{WE}$ LOW to High-Z Output	—	6	—	7	ns
$t_{LZWE}^{(2)}$	$\overline{WE}$ HIGH to Low-Z Output	3	—	3	—	ns

### Notes:

1. Test conditions assume signal transition times of 3ns or less, timing reference levels of 1.25V, input pulse levels of 0.4V to  $V_{DD}-0.3V$  and output loading specified in Figure 1a.
2. Tested with the loading specified in Figure 1b. Transition is measured  $\pm 500$  mV from steady-state voltage. Not 100% tested.
3. The internal write time is defined by the overlap of  $\overline{CE}$  LOW and  $\overline{WE}$  LOW. All signals must be in valid states to initiate a Write, but any one can go inactive to terminate the Write. The Data Input Setup and Hold timing are referenced to the rising or falling edge of the signal that terminates the Write.

## AC WAVEFORMS

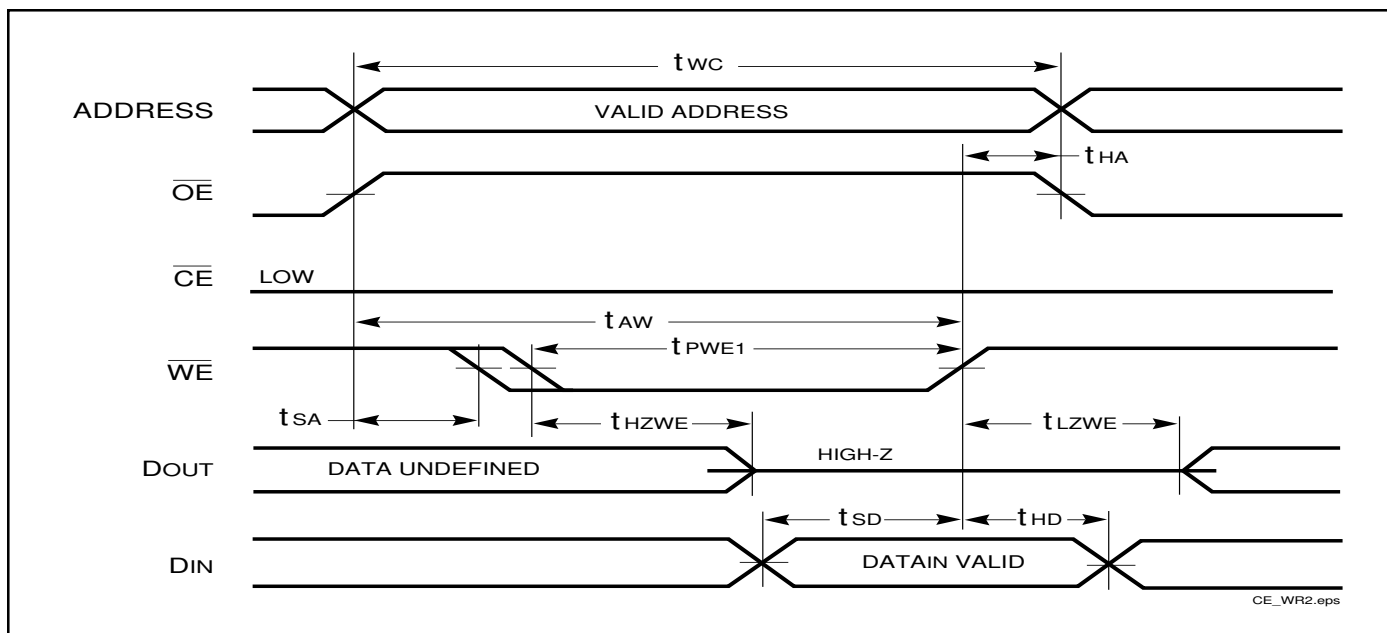
### WRITE CYCLE NO. 1<sup>(1,2)</sup> ( $\overline{CE}$ Controlled, $\overline{OE}$ = HIGH or LOW)



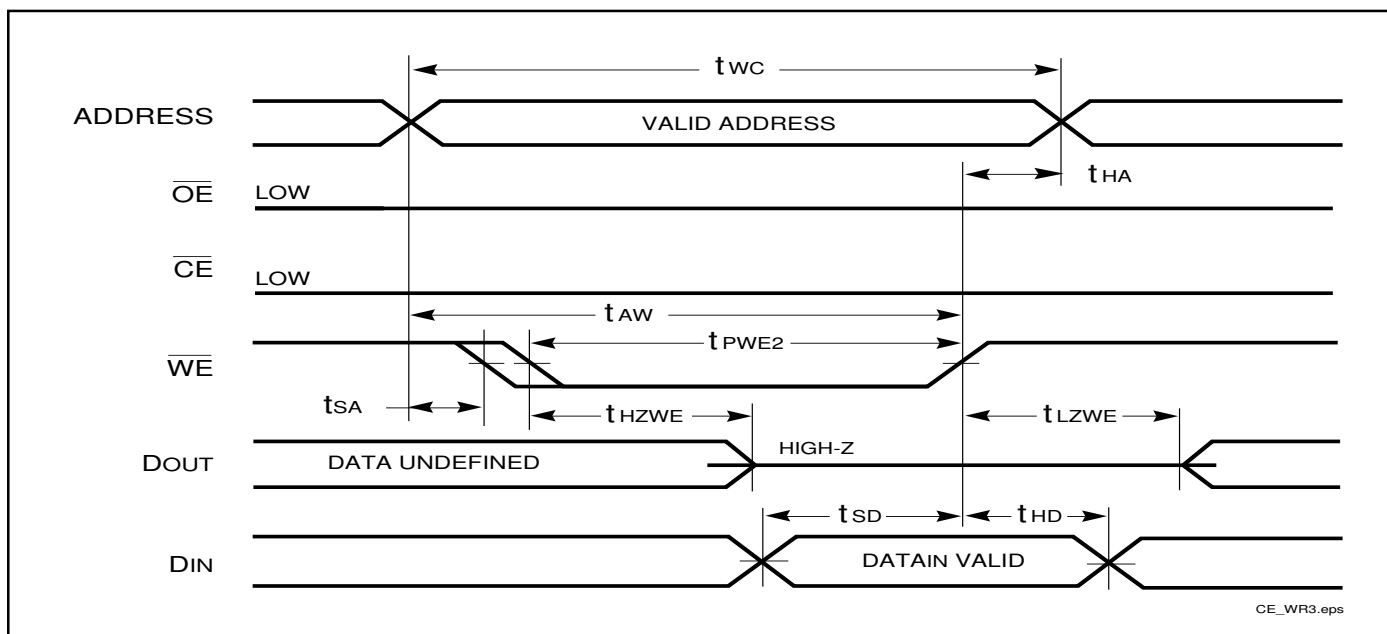


## AC WAVEFORMS

### WRITE CYCLE NO. 2<sup>(1)</sup> ( $\overline{WE}$ Controlled, $\overline{OE}$ = HIGH during Write Cycle)



### WRITE CYCLE NO. 3 ( $\overline{WE}$ Controlled: $\overline{OE}$ is LOW During Write Cycle)



#### Notes:

1. The internal write time is defined by the overlap of  $\overline{CE}$  LOW and  $\overline{WE}$  LOW. All signals must be in valid states to initiate a Write, but any one can go inactive to terminate the Write. The Data Input Setup and Hold timing are referenced to the rising or falling edge of the signal that terminates the Write.
2. I/O will assume the High-Z state if  $\overline{OE} > V_{IH}$ .

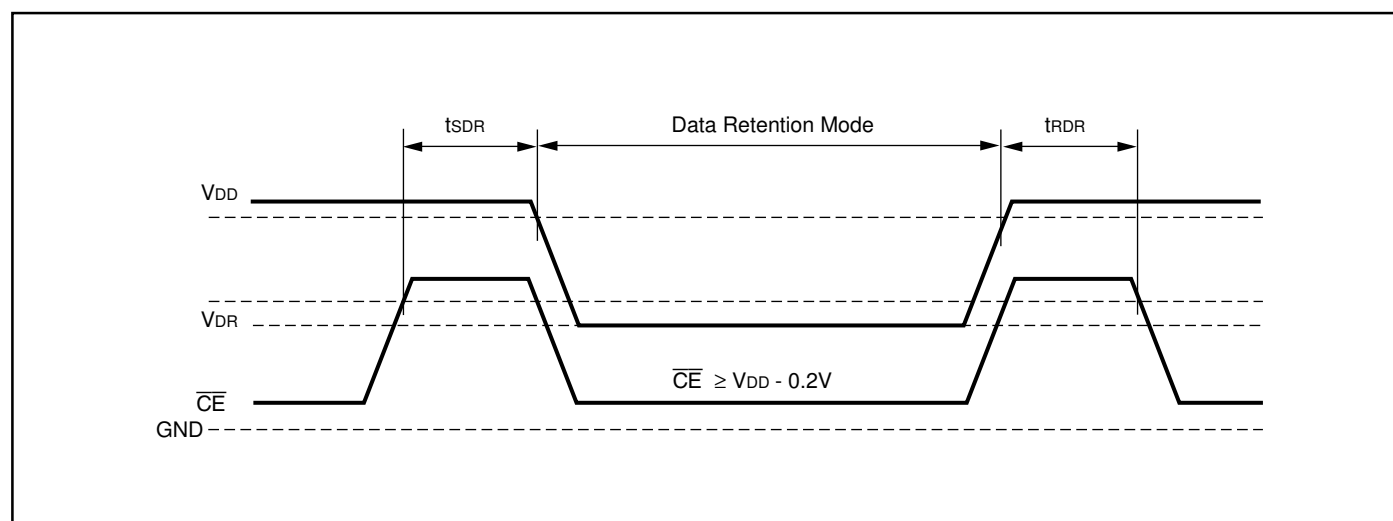
## DATA RETENTION SWITCHING CHARACTERISTICS

Symbol	Parameter	Test Condition	Operations	Min.	Typ. <sup>(1)</sup>	Max.	Unit
V <sub>DR</sub>	V <sub>DD</sub> for Data Retention	See Data Retention Waveform		1.8	—	3.6	V
I <sub>DR</sub>	Data Retention Current	V <sub>DD</sub> = 1.8V, $\overline{CE} \geq V_{DD} - 0.2V$	COM. IND. AUTO.	— — —	6 6 6	20 50 75	μA
t <sub>SDR</sub>	Data Retention Setup Time	See Data Retention Waveform		0	—	—	ns
t <sub>RDR</sub>	Recovery Time	See Data Retention Waveform		t <sub>RC</sub>	—	—	ns

### Note:

1. Typical values are measured at V<sub>DD</sub> = 2.5V, T<sub>A</sub> = 25°C. Not 100% tested.

## DATA RETENTION WAVEFORM ( $\overline{CE}$ Controlled)



## ORDERING INFORMATION

### Industrial Range: -40°C to +85°C

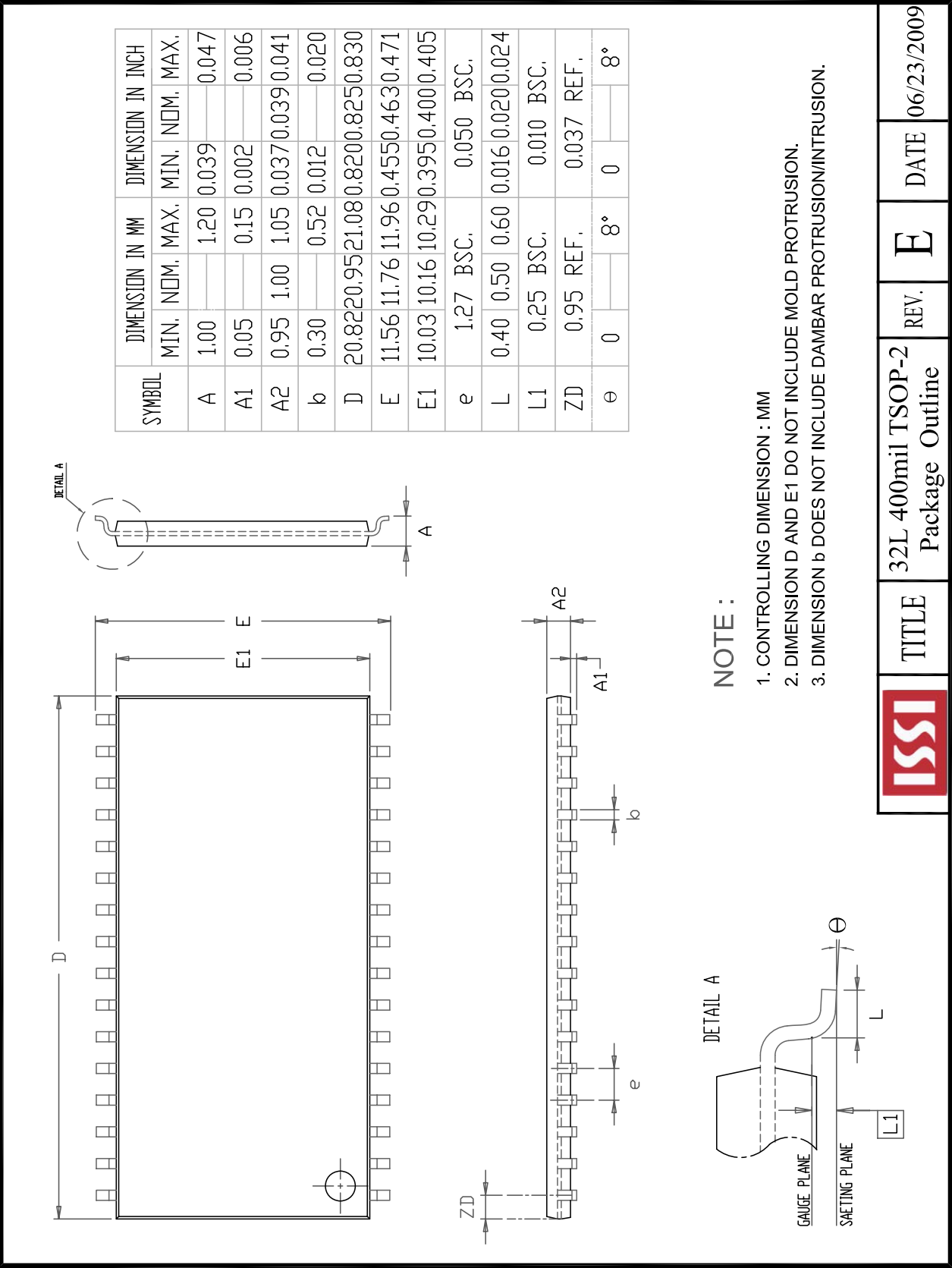
Speed (ns)	Order Part No.	Package
12	IS63WV1024BLL-12TI	32-pin TSOP (Type II)
	IS63WV1024BLL-12TLI	32-pin TSOP (Type II), Lead-free
	IS63WV1024BLL-12HI	sTSOP (Type I) (8mm x13.4mm)
	IS63WV1024BLL-12HLI	sTSOP (Type I) (8mm x13.4mm), Lead-free
	IS63WV1024BLL-12JLI	32-pin SOJ (300-mil), Lead-free
	IS63WV1024BLL-12BI	mBGA(6mmx8mm)
	IS63WV1024BLL-12BLI	mBGA(6mmx8mm), Lead-free

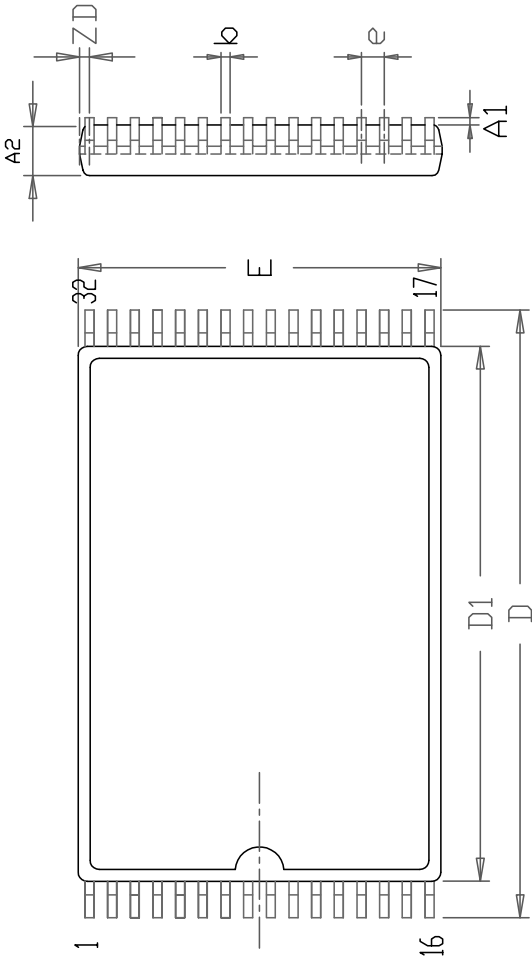
### Automotive Range (A3): -40°C to +85°C

Speed (ns)	Order Part No.	Package
15 (12*)	IS64WV1024BLL-15TA3	32-pin TSOP (Type II)
	IS64WV1024BLL-15TLA3	32-pin TSOP (Type II), Lead-free
	IS64WV1024BLL-15HA3	sTSOP (Type I) (8mm x13.4mm)
	IS64WV1024BLL-15HLA3	sTSOP (Type I) (8mm x13.4mm), Lead-free
	IS64WV1024BLL-15BA3	mBGA(6mmx8mm)
	IS64WV1024BLL-15BLA3	mBGA(6mmx8mm), Lead-free

#### Note:

1. Speed = 12ns for  $V_{DD} = 3.3V \pm 10\%$ . Speed = 15ns for  $V_{DD} = 2.5V-3.6V$ .

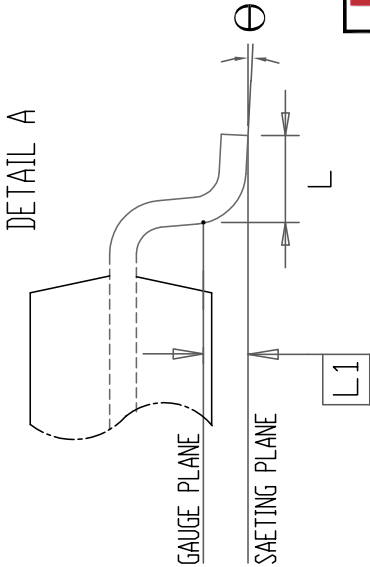




SYMBOL	DIMENSION IN MM			DIMENSION IN INCH		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.95		1.25	0.037		0.049
A1	0.05		0.15	0.002		0.008
A2	0.90		1.05	0.035		0.041
b	0.16		0.27	0.006		0.011
D	13.10	13.40	13.70	0.516	0.528	0.539
D1	11.70	11.80	11.90	0.461	0.465	0.469
E	7.90	8.00	8.10	0.311	0.315	0.319
e	0.50 BSC.			0.020 BSC.		
L	0.30	0.50	0.70	0.012	0.020	0.028
L1	0.25 BSC.			0.010 BSC.		
ZD	0.25 REF.			0.010 REF.		
Θ	0	3°	5°	0	3°	5°

NOTE :

1. CONTROLLING DIMENSION : MM
2. DIMENSION D1 AND E DO NOT INCLUDE MOLD PROTRUSION.
3. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION/INTRUSION.
4. Reference Document : JEDEC MO-183



TITLE

32L 8x13.4mm TSOP-1  
Package Outline

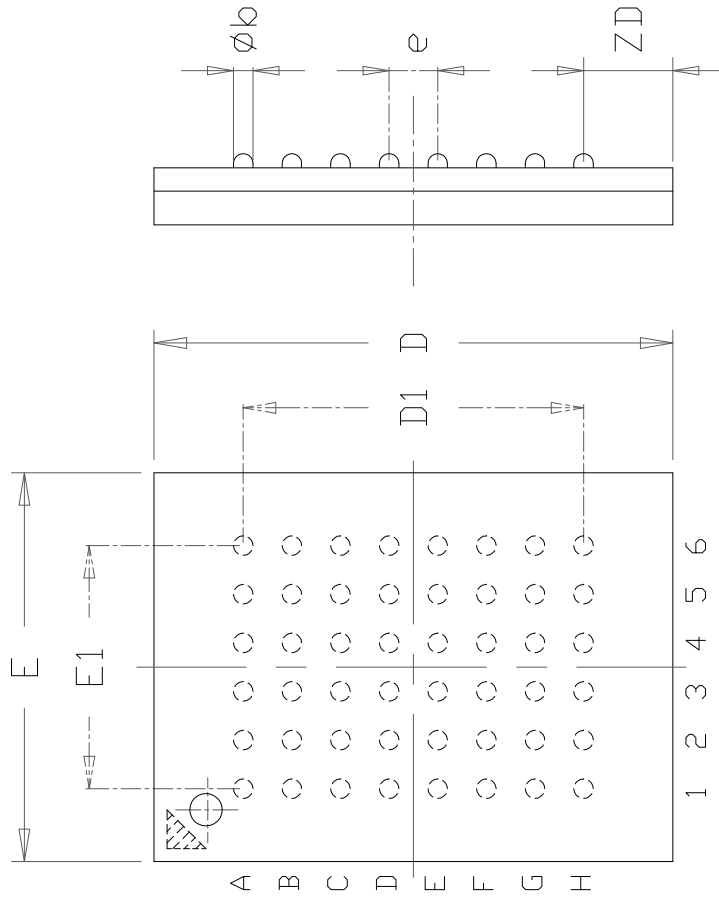
REV.

E

DATE

04/24/2009

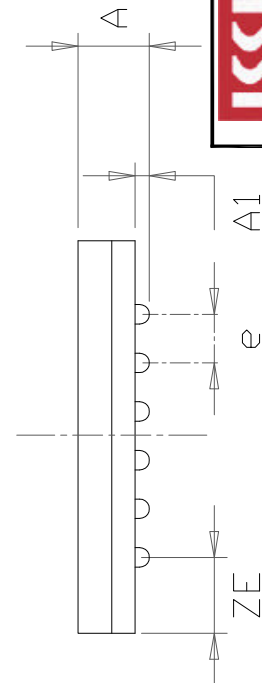
TOP VIEW



SYMBOL	DIMENSION IN MM			DIMENSION IN INCH		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A			1.20			0.047
A1	0.20		0.30	0.008		0.012
$\phi b$	0.30	0.35	0.40	0.012	0.014	0.016
D	7.90	8.00	8.10	0.311	0.315	0.319
D1	5.25	BSC		0.207	BSC	
E	5.90	6.00	6.10	0.232	0.236	0.240
E1	3.75	BSC		0.148	BSC	
e	0.75	BSC.		0.030	BSC.	
ZD	1.375	REF.		0.054	REF.	
ZE	1.125	REF.		0.044	REF.	

NOTE :

1. CONTROLLING DIMENSION : MM .
2. Reference document : JEDEC MO-207



TITLE

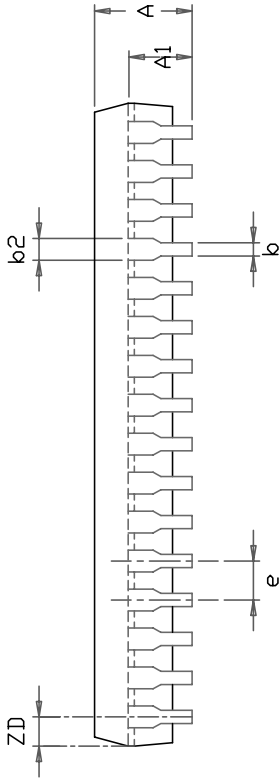
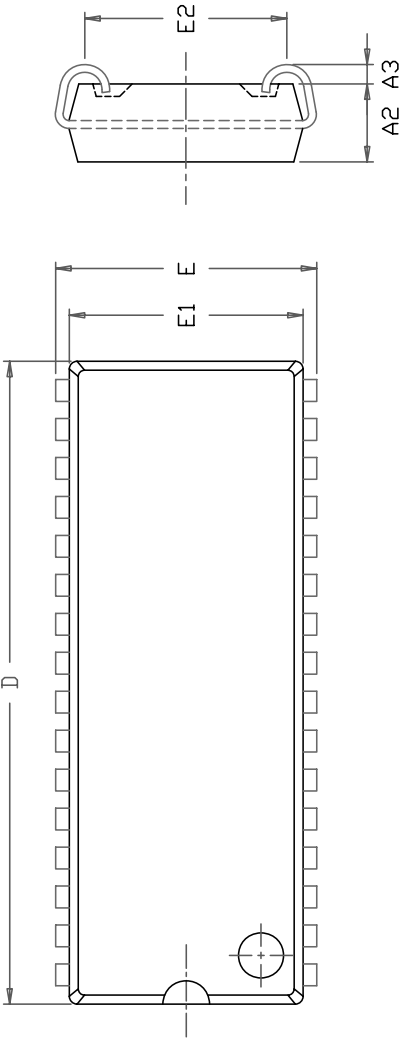
48L 6x8mm TF-BGA  
Package Outline

REV.

C

DATE

08/12/2008



SYMBOL	DIMENSION IN MM		DIMENSION IN INCH	
	MIN.	NOM. MAX.	MIN.	NOM. MAX.
A	3.05		3.76	0.148
A1	2.08		2.41	0.095
A2	2.41	2.54	2.67	0.100 0.105
A3	0.64		1.09	0.025 0.043
b	0.41		0.51	0.016 0.020
b2	0.66		0.81	0.026 0.032
D	20.82		21.09	0.820 0.830
E	8.38	8.51	8.64	0.330 0.335 0.340
E1	7.49	7.62	7.75	0.295 0.300 0.305
E2	6.48		6.99	0.255 0.275
e		1.27 BSC.		0.050 BSC.
ZD		0.95 REF.		0.037 REF.

NOTE :

- 1. CONTROLLING DIMENSION : MM
- 2. DIMENSION D AND E1 DO NOT INCLUDE MOLD PROTRUSION.
- 3. DIMENSION b2 DOES NOT INCLUDE DAMBAR PROTRUSION/INTRUSION.



32L 300mil SOJ  
Package Outline

TITLE

REV.

C

DATE

08/14/2009